5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-88 package.

Features

- Protects up to 5-Line in a Single SC-88 Package
- Peak Power Dissipation 100 W (8 x 20 µs Waveform)
- ESD Rating of Class 3B (Exceeding 8 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model.
- Compliance with IEC 61000–4–2 (ESD) 15 kV (Air), 8 kV (Contact)
- Flammability Rating of UL 94 V-0
- Pb-Free Package is Available

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T_J=25°C unless otherwise specified)

Symbol	Rating	Value	Unit
P _{PK} 1	Peak Power Dissipation 8 x 20 μs Double Exponential Waveform (Note 1)	100	W
TJ	Operating Junction Temperature Range	-40 to 125	°C
T _{STG}	Storage Temperature Range	-55 to 150	°C
T _L	Lead Solder Temperature (10 s)	260	°C
ESD	Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD)	16000 400 15000 15000	V

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Nonrepetitive current pulse per Figure 3.



ON Semiconductor®

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SC-88 FIVE TRANSIENT VOLTAGE SUPPRESSOR 100 W PEAK POWER

MARKING DIAGRAM

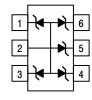


SC-88 CASE 419B STYLE 24



6J = SMF05C 6K = SMF12C 6L = SMF15C 6M = SMF24C M = Date Code

PIN ASSIGNMENT



- PIN1. CATHODE
 - 2. ANODE
 - 3 CATHODE
 - 4. CATHODE
 - 5. CATHODE
 - 6. CATHODE

ORDERING INFORMATION

Device	Package	Shipping [†]
SMF05CT1	SC-88	3000/Tape & Reel
SMF05CT2*	SC-88	3000/Tape & Reel
SMF05CT2G*	SC-88 (Pb-Free)	3000/Tape & Reel
SMF12CT1	SC-88	3000/Tape & Reel
SMF15CT1	SC-88	3000/Tape & Reel
SMF24CT1	SC-88	3000/Tape & Reel

- †For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.
- *The "T2" suffix refers to an alternate tape & reel orientation.

SMF05C ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			5.0	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	6.2		7.2	V
Reverse Leakage Current	I _R	V _{RWM} = 5 V		0.07	5.0	μΑ
Clamping Voltage	V _C	I _{PP} = 5 A (8 x 20 μs Waveform)			9.8	V
Clamping Voltage	V _C	I _{PP} = 8 A (8 x 20 μs Waveform)			12.5	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			8.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		80	130	pF

SMF12C ELECTRICAL CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			12	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	13.3		15	V
Reverse Leakage Current	I _R	V _{RWM} = 12 V		0.01	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 3 A (8 x 20 μs Waveform)			21	V
Clamping Voltage	V _C	I _{PP} = 6 A (8 x 20 μs Waveform)			23	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			6.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		40	60	pF

SMF15C ELECTRICAL CHARACTERISTICS ($T_J = 25$ °C, unless otherwise specified)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V _{RWM}	(Note 2)			15	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	17		19	V
Reverse Leakage Current	I _R	V _{RWM} = 15 V		0.01	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 1 A (8 x 20 μs Waveform)			23	V
Clamping Voltage	V _C	I _{PP} = 5 A (8 x 20 μs Waveform)			29	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			5.0	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		33	45	pF

$\textbf{SMF24C ELECTRICAL CHARACTERISTICS} \ (T_J = 25^{\circ}\text{C}, \text{ unless otherwise specified})$

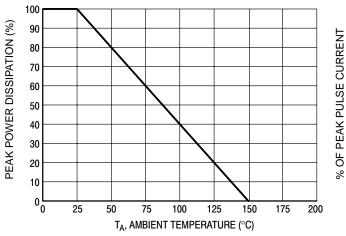
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Reverse Working Voltage	V_{RWM}	(Note 2)			24	V
Breakdown Voltage	V_{BR}	I _T = 1 mA, (Note 3)	26.7		32	V
Reverse Leakage Current	I _R	V _{RWM} = 24 V		0.01	1.0	μΑ
Clamping Voltage	V _C	I _{PP} = 1 A (8 x 20 μs Waveform)			40	V
Clamping Voltage	V _C	I _{PP} = 2.5 A (8 x 20 μs Waveform)			44	V
Maximum Peak Pulse Current	I _{PP}	8 x 20 μs Waveform			2.5	Α
Capacitance	CJ	V _R = 0 V, f = 1 MHz (Line to GND)		21	25	pF

^{2.} TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.

3. V_{BR} is measured at pulse test current I_T.

TYPICAL PERFORMANCE CURVES

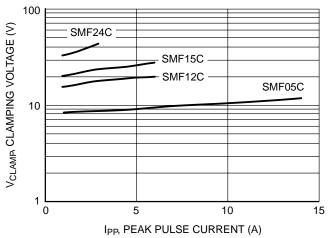
(T_J = 25°C unless otherwise specified)



100 PEAK VALUE $I_{\mbox{\scriptsize RSM}}$ @ 8 $\mu \mbox{\scriptsize s}$ 90 PULSE WIDTH (tp) IS DEFINED 80 AS THAT POINT WHERE THE 70 PEAK CURRENT DECAY = 8 μs 60 HALF VALUE $I_{RSM}/2$ @ 20 μs 50 40 30 20 10 20 40 60 80 0 t, TIME (μs)

Figure 1. Pulse Derating Curve

Figure 2. $8 \times 20~\mu s$ Pulse Waveform



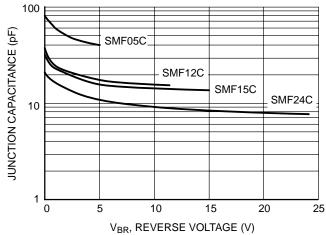


Figure 3. Clamping Voltage vs Peak Pulse Current

Figure 4. Junction Capacitance vs Reverse Voltage

PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363

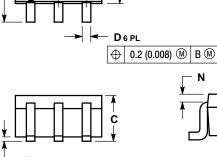
CASE 419B-02 ISSUE 02U

- DIMENSIONING AND TOLERANCING PER ANSI
- 2. CONTROLLING DIMENSION: INCH.
- 419B-01 OBSOLETE, NEW STANDARD 419B-02.

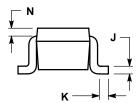
	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65	BSC
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20	REF
S	0.079	0.087	2 00	2 20

STYLE 24: PIN 1. CATHODE

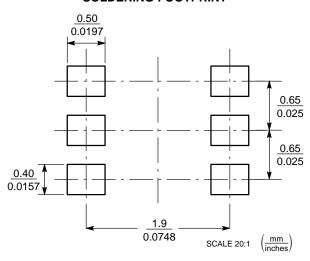
- 2 ANODE
- 3. CATHODE 4. CATHODE
- 6 CATHODE



-B-



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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